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Vishay Semiconductor/Diodes Division SB1H100-E3/73

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of SB1H100-E3/73 - DIODE SCHOTTKY 100V 1A DO204AL

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SB1H90, SB1H100

Vishay General Semiconductor

High Voltage Schottky Plastic Rectifier

High Barrier Technology for Improved High Temperature Performance

DO-204AL (DO-41)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	1.0 A				
V _{RRM} 90 V, 100 V					
I _{FSM}	50 A				
V _F	0.62 V				
I _R	1.0 μA				
T _J max.	175 °C				
Package	DO-204AL				
Diode variations	Single				

FEATURES

- High barrier technology for improved high $T_{\rm J}$
- Guardring for overvoltage protection
- Low power losses and high efficiency
- Low forward voltage drop
- Very low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in middle voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: DO-204AL (DO-41) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SB1H90	SB1H100	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	90	100	V	
Maximum RMS voltage	V _{RMS}	63 70		V	
Maximum DC blocking voltage	V _{DC}	90 100		V	
Maximum average forward rectified current	I _{F(AV)}	1.0		A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	50		А	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Peak repetitive reverse surge current at $t_p = 2.0 \ \mu s$, 1 kHz	I _{RRM}	1.0		A	
Maximum operating junction temperature	TJ	175		°C	
Storage temperature range	T _{STG}	- 55 to + 175			



COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	SB1H90	SB1H100	UNIT	
Maximum instantaneous forward voltage	I _F = 1.0 A	T _J = 25 °C	V _F ⁽¹⁾	0.77			
		T _J = 125 °C		0.62		V	
	I _F = 2.0 A	T _J = 25 °C		VF ()	0.	86	v
		T _J = 125 °C		0.70			
Maximum reverse current at rated V_R		T _J = 25 °C	I _R ⁽²⁾	1	.0	μA	
		T _J = 125 °C		0	.5	mA	

Notes

⁽¹⁾ Pulse test: 300 ms pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	OL SB1H90 SB1H100		UNIT		
Maximum thermal resistance	R _{0JA} ⁽¹⁾	57		°C/W		
	R _{0JL} ⁽¹⁾	15				

Note

 $^{(1)}\,$ PCB mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	T WEIGHT (g) PREFERRED PACKAGE CODE BASE QUANTITY		DELIVERY MODE		
SB1H100-E3/54	0.34	54	5500	13" diameter paper tape and reel		
SB1H100-E3/73	0.34	73	3000	Ammo pack packaging		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

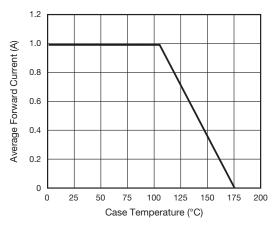


Fig. 1 - Forward Current Derating Curve

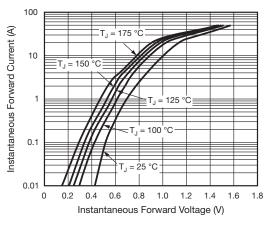
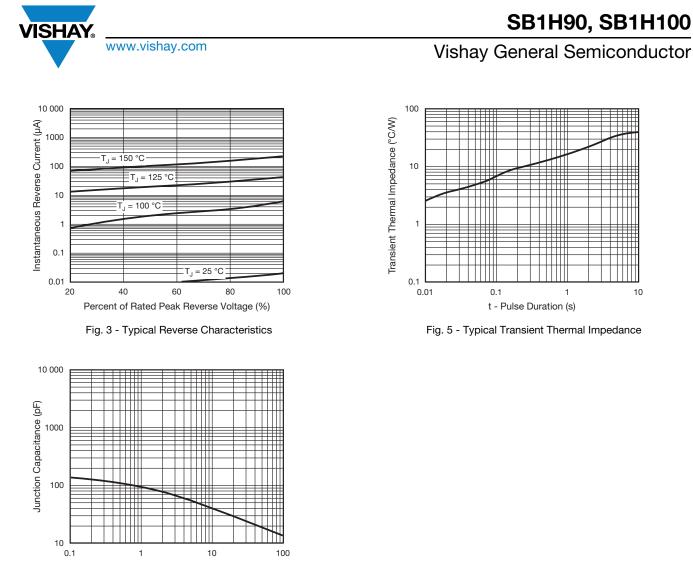


Fig. 2 - Typical Instantaneous Forward Characteristics

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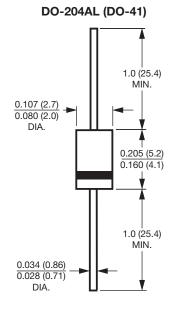
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Reverse Voltage (V)

Fig. 4 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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